

Erratum: Electronic properties of silole-based organic semiconductors [J. Chem. Phys. 121, 9031 (2004)]

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Citation: *J. Chem. Phys.* **122**, 099901 (2005); doi: 10.1063/1.1854624

View online: <http://dx.doi.org/10.1063/1.1854624>

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(Received 1 December 2004; accepted 9 December 2004; published online 1 March 2005)

[DOI: 10.1063/1.1854624]

The third author's name was misspelled in the original article. The correct spelling is Z. H. Kafafi.